NSN 5961-00-998-4566



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-00-998-4566 **Inclosure Material:** Metal **Overall Length:** Between 0.719 inches and 0.764 inches Overall Diameter: Between 0.622 inches and 0.628 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case and mounting hardware **Overall Width Across Flats:** 0.750 inches **Thread Size:** 0.625 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 8.5 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius ambient air **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator: Terminal Type And Quantity:** 2 tab, solder lug **Specification Data:** 81349-mil-19500/335 government specification

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Shelf Life:
N/a
Unit Of Measure:
-Demilitarization:

No

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